400.Garden City, Plaza
Garden City, New York 51:15
(516) 742-4343 - Telephone
(516) 742-4366 - Facsimile
e:mail: intrprop@ssmp.com

## SCULLY, SCOTT, MURPHY & PRESSER

### RECEIVED CENTRAL FAX CENTER

AUG 3 1 2004



To:		miner C.Q. Nguyen up Art Unit: 2811		From:	Leslie S. Szivos, P	h.D.
Fax:	703	-872-9306		Pages:	7 including cover	
Phone	:			Date:	8/31/2004	
Re:	U.S.	chiang Chen, et al. Patent Appln. No. 1 Docket: YOR92003		CC:		
XX Urg	jent	☐ For Review	☐ Please Com	iment	☐ Please Reply	☐ Please Recycle
Dear Si	r:		· .			

----

The following is attached hereto:

- 1. Amendment Transmittal in duplicate
- Response under 37 CFR 1.111 and 1.143
- 3. Certificate of Facsimile

## **BEST AVAILABLE COPY**

CONFIDENTIALITY: The documents accompanying this facsimile transmission may contain information which is either confidential or legally privileged and is intended only for the authorized use of the individual or entity named above without right or publication or republication, dissemination or disclosure except as expressly set forth or established by course of dealing. All rights are reserved. If you are not the intended recipient, you are hereby notified that any disclosure, copying, distribution or use of the contents of this facsimile is prohibited. If you received this transmission in error, please notify us immediately by telephone to arrange for return of the documents.

If you have any problems concerning this facsimile, please call (516) 742-4343 and ask for Susan Formicola at Ext 511.

CERTIFICATES OF THE CAPPELL OF THE C	VANSMISSION BY FAC	SIMILE (37 CFR 1.8)	Docket No. X0R920030586US1*(17201)
Application No. 10/700,085	Filing Date 11/3/2003	Examiner C.Q. Nguyen	Group Art Unit
	R FABRICATING SiGe-ON-II	NSULATOR (SGOI) AND Ge-ON	
I hereby certify that this _		NSE UNDER 37 CFR 1.111 AND (Identify type of correspondence)	_
-		nt and Trademark Office (Fax. N	o. <u>703-872-9306</u> )
On August 31, 20 (Date)	<del>// / / / / / / / / / / / / / / / / / /</del>		
		Leslie S. Szivos,	.Ph.D.
·			Signing Certificate)
•		(Signature)	
		(	,
	Note: Fack namer must be	ave its own certificate of mailing.	
	14016. Estu papet must ne	ive its own termicate of maining,	
		,	A.
i			

CERTIFICATE OF Applicant(s) ** Fze-chian	TRANSMISSION BY FAC	SIMILE (37 CFR 1.8)	Docket No. YOR920030586US1 (1/201)
Application No. 10/700,085	Filing Date 11/3/2003	g Date Examiner Gr	
Invention: METHOD F SUBSTRATI	FOR FABRICATING SIGE-ON-IN ES	NSULATOR (SGOI) AND Ge-	ON-INSULATOR (GOI)
I hereby certify that this	RESPON	NSE UNDER 37 CFR 1.111 AN (Identify type of correspondence)	D 1.143
is being facsimile transn	nitted to the United States Paten		No. <u>703-872-9306</u> )
on August 31			
(Date)		•	
		Yanka C Cala	A
	<del></del>	Leslie S. Szivo (Typed or Printed Name of Herse	08, P.C.V. son Sizying Certificate)
		7. Signature	1
		(Signature	<b>9</b>
	Note: Each paper must ha	ave its own certificate of mailing.	
		- • .	
		- -	
			-

AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Tze-chiang Chen, et al.					Docket No. YOR920030586US1 (17201)	
Application No. 10/700,085	Filing Date 11/3/2003	Examiner C.Q. Nguyen	Customer 1 23389	No. Group Art Unit	Confirmation No. 2805	
Invention: METHOD FOR FABRICATING SIGE-ON-INSULATOR (SGOI) AND GE-ON-INSULATOR (GOI) SUBSTRATES						
COMMISSIONER FOR PATENTS:  Transmitted herewith is an amendment in the above-identified application.  The fee has been calculated and is transmitted as shown below.						
		CLAIMS AS AM	ENDED			
	CLAIMS REMAINING	HIGHEST#	NUMBER EXTRA		ADDITIONAL	
	AFTER AMENDMENT	PREV. PAID FOR	CLAIMS PRESENT	RATE	FEE	
TOTAL CLAIMS	68 -	68 =	0	x \$18.00	\$0.00	
INDEP. CLAIMS	6 -	6 =	0	x \$86.00	\$0.00	
Multiple Depender	nt Claims (check if app	olicable)			\$0.00	
		TOTAL ADDITIONAL	FEE FOR THIS AM	ENDMENT	\$0.00	
☐ Please ch ☐ A check ir 図 The Direct communict 図 Any a	cation or credit any over additional filing fees re		the following fees count 50-0510	)/ <b>IBM</b>	S	
Leslie S. Szivos, I Registration No. 3	Ph.D.		class mall under 37 C. for Patents, R.O. Box 1	document and fee is with the U.S. F.R. 1.8 and is eddress 450, Alexandria, VA 22 of Person Mailing Corre	Postal Service as first ed to the Commissioner (313-1450.	
cc:			Typed or Printed Name of Person Mailing Correspondence			

				3 1	<u> </u>		
AMENDMENT TRANSMITTAL LETTER (Large Entity) Applicant(s): Tze-chiang(chen, et al.					Docket No		
					1 - 1 - 1 - 1 - 1 - 1		
Application No.	Filing Date	Examiner	Customer	No. Group Art U	nit Confirmation No.		
10/700,085	11/3/2003	C.Q. Nguyen	23389	2811	2805		
Invention: METHOD FOR FABRICATING SIGE-ON-INSULATOR (SGOI) AND GE-ON-INSULATOR (GOI) SUBSTRATES							
		COMMISSIONER FO	R PATENTS:				
Transmitted herev	with is an amendment	in the above-identified a	application.				
The fee has been	calculated and is trans	smitted as shown below					
		CLAIMS AS AM	ENDED				
	CLAIMS REMAINING	HIGHEST#	NUMBER EXTRA		ADDITIONAL		
	AFTER AMENDMENT	PREV. PAID FOR	CLAIMS PRESENT	RATE	FEE		
TOTAL CLAIMS	68 -	68 =	0	x \$18.00	\$0.00		
INDEP. CLAIMS	6 -	6 ≐	0	x \$86.00	\$0.00		
Multiple Dependent Claims (check if applicable)				\$0.00			
TOTAL ADDITIONAL FEE FOR THIS AMENDMENT \$0.0					\$0.00		
<ul> <li>No additional fee is required for amendment.</li> <li>□ Please charge Deposit Account No. in the amount of</li> <li>□ A check in the amount of to cover the filling fee is enclosed.</li> <li>☑ The Director is hereby authorized to charge payment of the following fees associated with this communication or credit any overpayment to Deposit Account 50-0510/IBM</li> <li>☑ Any additional filing fees required under 37 C.F.R. 1.16.</li> <li>☑ Any patent application processing fees under 37 CFR 1.17.</li> </ul>							
Leslie S. Szivos, Ph.D.  Registration No. 39,394  I certify that this document and fee is being deposited on with the U.S. Postal Service as first class mall-under 37 C.F.R. 1.8 and is addressed to the Commissioner							
cc:				of Person Mailing Co	prrespondence		

# This Page is Inserted by IFW Indexing and Scanning Operations and is not part of the Official Record

### BEST AVAILABLE IMAGES

Defective images within this document are accurate representations of the original documents submitted by the applicant.

Defects in the images include but are not limited to the items checked:

BLACK BORDERS
☐ IMAGE CUT OFF AT TOP, BOTTOM OR SIDES
☐ FADED TEXT OR DRAWING
☐ BLURRED OR ILLEGIBLE TEXT OR DRAWING
☐ SKEWED/SLANTED IMAGES
☐ COLOR OR BLACK AND WHITE PHOTOGRAPHS
GRAY SCALE DOCUMENTS
☐ LINES OR MARKS ON ORIGINAL DOCUMENT
☐ REFERENCE(S) OR EXHIBIT(S) SUBMITTED ARE POOR QUALITY
OTHER:

#### IMAGES ARE BEST AVAILABLE COPY.

As rescanning these documents will not correct the image problems checked, please do not report these problems to the IFW Image Problem Mailbox.